

# **Device Modeling Report**

COMPONENTS: Light-Emitting Diode (LED) STANDARD  
PART NUMBER: OSWT5161A  
MANUFACTURER: OPTO SUPPLY  
REMARK: TA=0 degree C

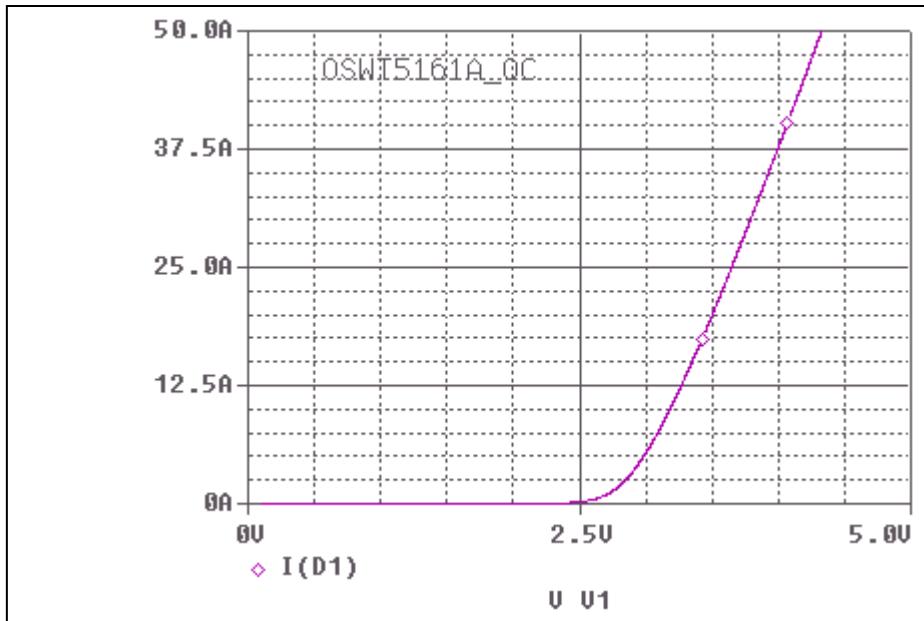


**Bee Technologies Inc.**

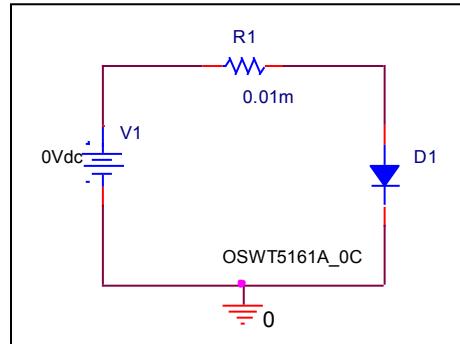
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

### Circuit Simulation Result

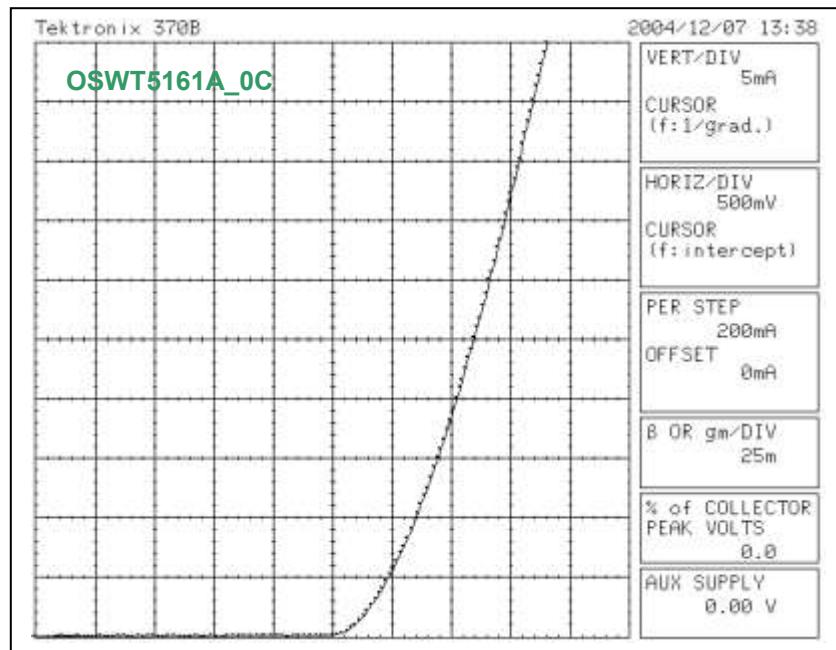


### Evaluation Circuit



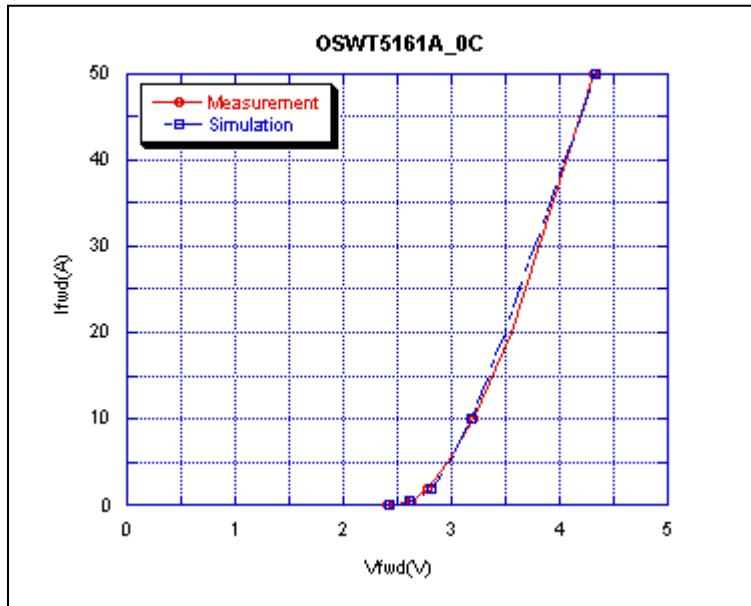
## Forward Current Characteristic

## Reference



## Comparison Graph

Circuit Simulation Result

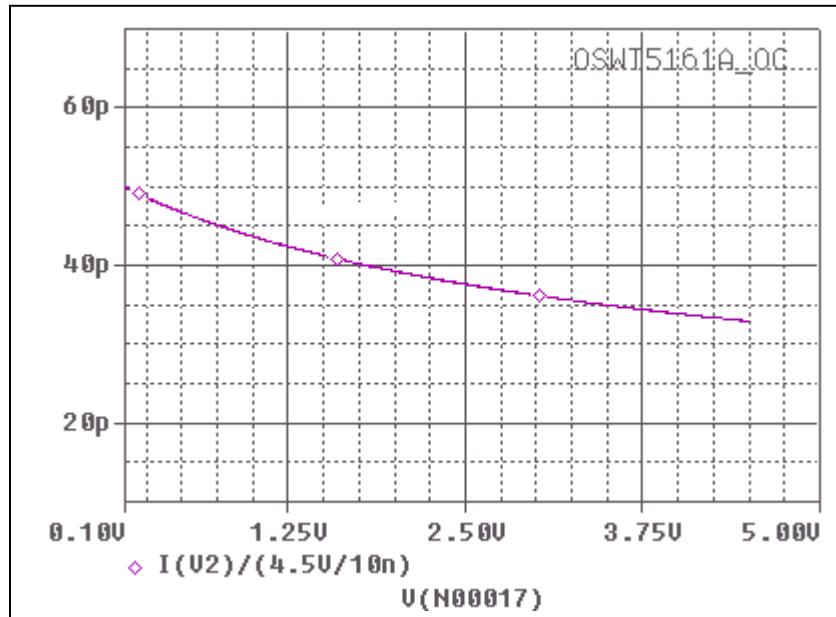


Simulation Result

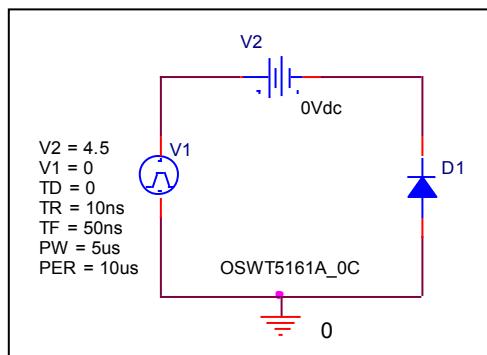
$I_{fwd}$ (A)	$V_{fwd}$ (V) Measurement	$V_{fwd}$ (V) Simulation	%Error
0.1	2.41	2.427	0.705
0.2	2.545	2.505	1.5717
0.5	2.63	2.616	0.5323
1	2.69	2.706	0.5947
2	2.77	2.808	1.3718
5	2.955	2.984	0.9813
10	3.2	3.183	0.5312
20	3.55	3.503	1.3239
50	4.31	4.327	0.3944

## Capacitance Characteristic

### Circuit Simulation Result

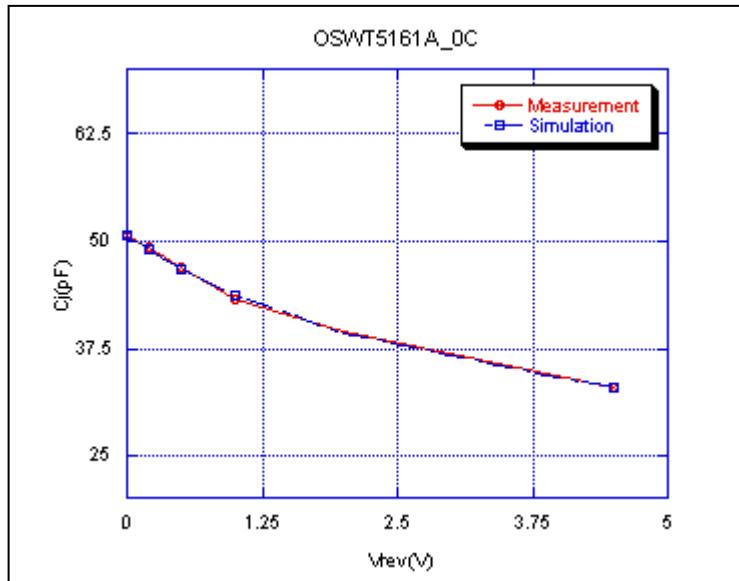


### Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

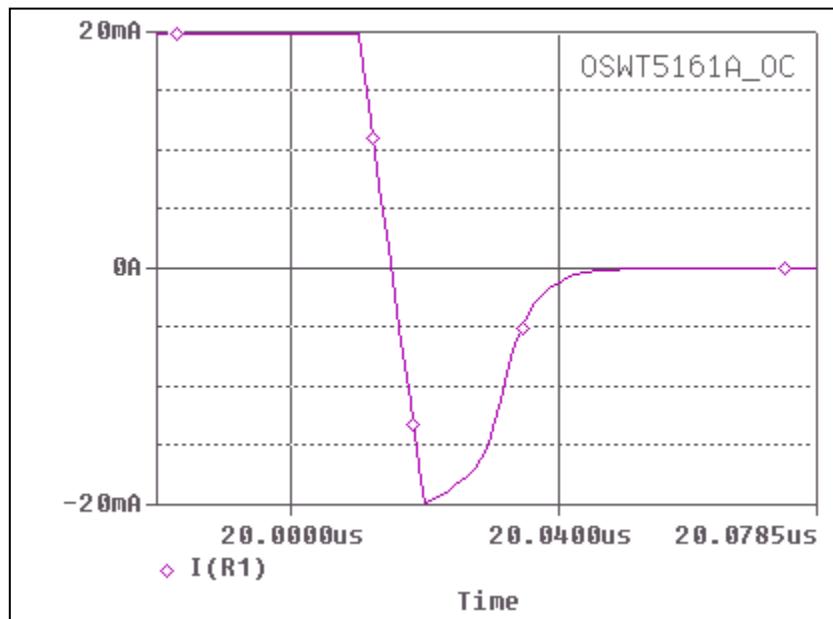


Simulation Result

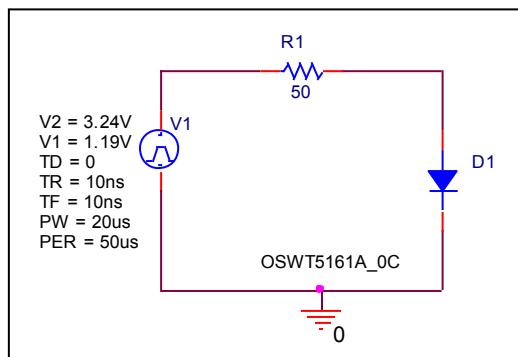
$V_{rev}(V)$	$C_j(pF)$ Measurement	$C_j(pF)$ Simulation	%Error
0	50.63	50.63	0
0.1	49.95	49.92	0.0600
0.2	49.25	49.07	0.3654
0.5	47.01	46.71	0.6381
1	43.15	43.65	1.1587
2	39.5	39.3	0.5063
4.5	32.86	32.9	0.1217

## Reverse Recovery Characteristic

### Circuit Simulation Result



### Evaluation Circuit

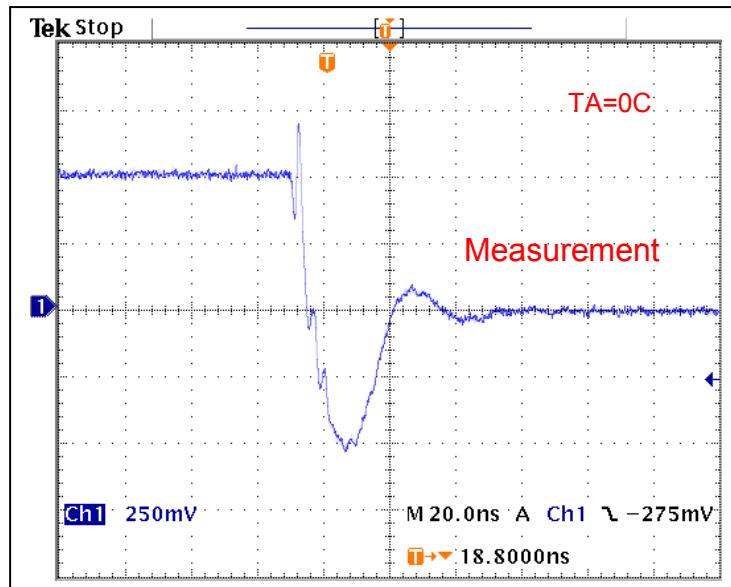


Compare Measurement vs. Simulation

Symbol	Measurement	Unit	Simulation	Unit	%Error
$T_{rr} = trj + trb$	22.4	ns	22.6	ns	0.982

## Reverse Recovery Characteristic

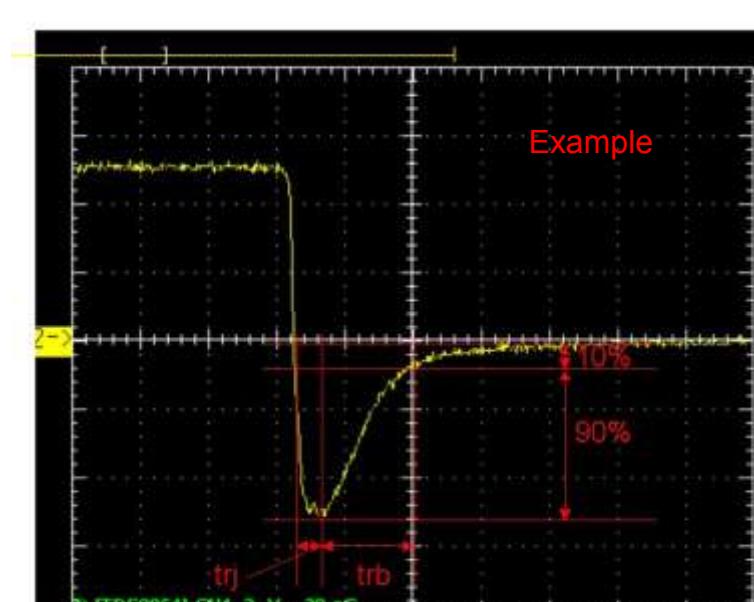
## Reference



Trj =9.2(ns)

Trb=13.2(ns)

Conditions: Ifwd=Irev=0.02(A), RI=50



Relation between trj and trb